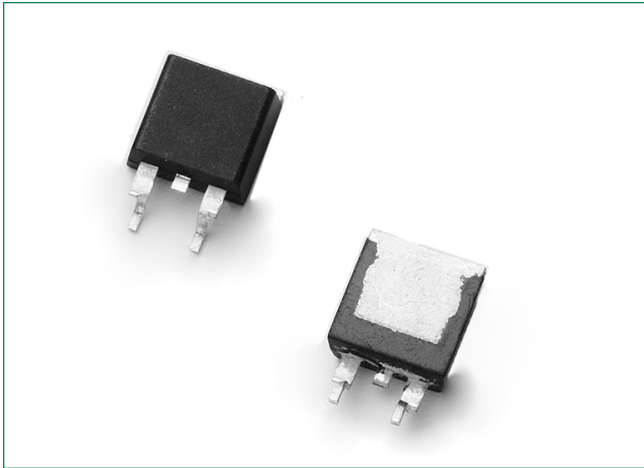# MAC4DHM

Description

The MAC4DHM is designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

Features

- Small Size Surface Mount DPAK Package
- Passivated Die for Reliability and Uniformity
- Four–Quadrant Triggering
- Blocking Voltage to 600 V
- On–State Current Rating of 4.0 A RMS at 93°C
- Low Level Triggering and Holding Characteristics
- Epoxy Meets UL 94 V–0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V Machine Model, C > 400V
- Lead–Free Packages are Available

Pin Out
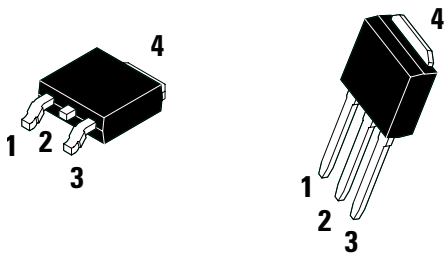
Functional Diagram

MT 2   MT 1

G
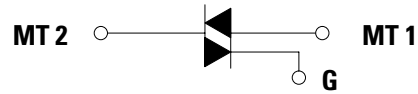
Maximum Ratings (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, T_J = -40° to 110°C)	V_{DRM}, V_{RRM}	600	V
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, T_C = 93°C)	$I_{T(RMS)}$	4.0	A
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T_C = 110°C)	I_{TSM}	40	A
Circuit Fusing Consideration (t = 8.3 msec)	I^2t	6.6	A²sec
Peak Gate Current (Pulse Width ≤ 20 μsec, T_C= 108°C)	I_{GM}	4.0	A
Peak Gate Power (Pulse Width ≤ 10 μsec, T_C= 108°C)	P_{GM}	2.0	W
Peak Gate Voltage (Pulse Width ≤ 20 μsec, $_C T$= 93°C)	V_{GM}	5.0	V
Average Gate Power (t = 8.3 msec, T_C= 108°C)	$P_{G(AV)}$	1.0	W
Operating Junction Temperature Range	T_J	-40 to +110	°C
Storage Temperature Range	T_{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics

Rating		Symbol	Value	Unit
Thermal Resistance,	Junction−to−Case (AC) Junction−to−Ambient Junction−to−Ambient (Note 2)	$R_{\theta JC}$ $R_{\theta JA}$ $R_{\theta JA}$	3.5 88 80	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8″ from case for 10 seconds		T_L	260	°C

2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.
3. 1/8" from case for 10 seconds.

Electrical Characteristics - OFF (T_J = 25°C unless otherwise noted ; Electricals apply in both directions)

Characteristic		Symbol	Min	Typ	Max	Unit
Peak Repetitive Blocking Current (V_D = V_{DRM} = V_{RRM}, Gate Open)	T_J = 25°C	I_{DRM}, I_{RRM}	-	-	0.01	mA
	T_J = 110°C		-	-	2.0	

Electrical Characteristics - ON (T_J = 25°C unless otherwise noted; Electricals apply in both directions)

| Characteristic			Symbol	Min	Typ	Max	Unit
Peak On−State Voltage (Note 4) (I_{TM} = ±6.0 A)			V_{TM}	–	1.3	1.6	V
Gate Trigger Current (Continuous dc) (V_D = 12 V, R_L = 100 Ω)		MT2(+), G(+)	I_{GT}	–	1.8	5.0	mA
		MT2(+), G(−)		–	2.1	5.0	
		MT2(−), G(−)		–	2.4	5.0	
		MT2(−), G(+)		–	4.2	10	
Holding Current (V_D = 12 V, Gate Open, Initiating Current = ±200 mA))			I_H	-	1.5	15	mA
Gate Non−Trigger Voltage (Continuous dc) − (V_D = 12 V, R_L = 100 Ω, T_J = 110°C) All Four Quadrants			V_{GD}	0.1	0.4	-	V
Latching Current	(V_D = 12 V, I_G = 5.0 mA)	MT2(+), G(+)	I_L	–	1.75	10	mA
	(V_D = 12 V, I_G = 5.0 mA)	MT2(+), G(−)		–	5.2	10	
	(V_D = 12 V, I_G = 5.0 mA)	MT2(−), G(−)		–	2.1	10	
	(V_D = 12 V, I_G = 10 mA)	MT2(−), G(+)		–	2.2	10	
Gate Trigger Voltage (Continuous dc) (V_D = 12 V, R_L = 100 Ω)		MT2(+), G(+)	V_{GT}	0.5	0.62	1.3	V
		MT2(+), G(−)		0.5	0.57	1.3	
		MT2(−), G(−)		0.5	0.65	1.3	
		MT2(−), G(+)		0.5	0.74	1.3	

4. Indicates Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.

Dynamic Characteristics

Characteristic	Symbol	Min	Typ	Max	Unit
Rate of Change of Commutating Current (V_D = 200 V, I_{TM} = 1.8 A, Commutating dv/dt = 1.0 V/μsec, T_J = 110°C, f = 250 Hz, CL = 5.0 μfd, LL = 80 mH, RS = 56 Ω, CS = 0.03 μfd) With snubber see Figure 11	(dI/dt)c	-	3.0	–	A/ms
Critical Rate of Rise of Off-State Voltage (V_D = 0.67 x V_{DRM}, Exponential Waveform, Gate Open, T_J = 110°C)	dV/dt	20	-	–	V/μs

Voltage Current Characteristic of SCR

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I_{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Reverse Off State Voltage
I_{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
I_H	Holding Current
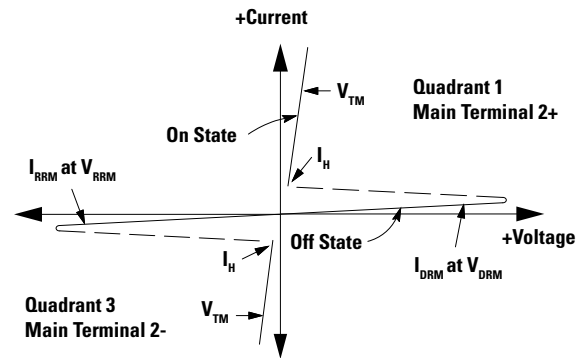
Quadrant Definitions for a Triac
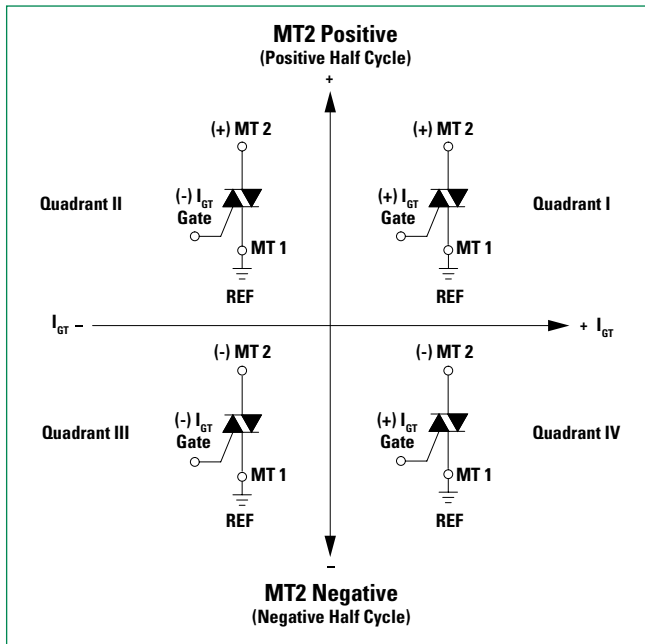
All Polarities are referenced to MT1.
With in-phase signals (using standard AC lines) quadrants I and III are used

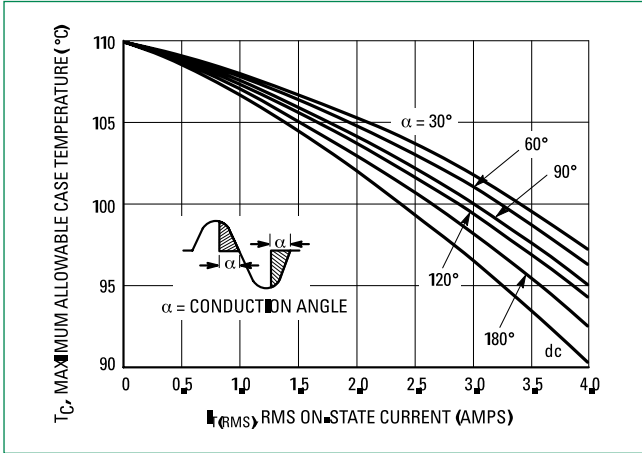## Figure 1. Typical RMS Current Derating
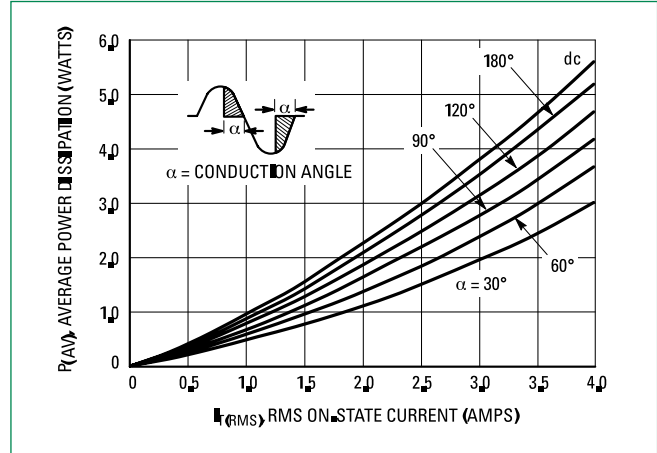

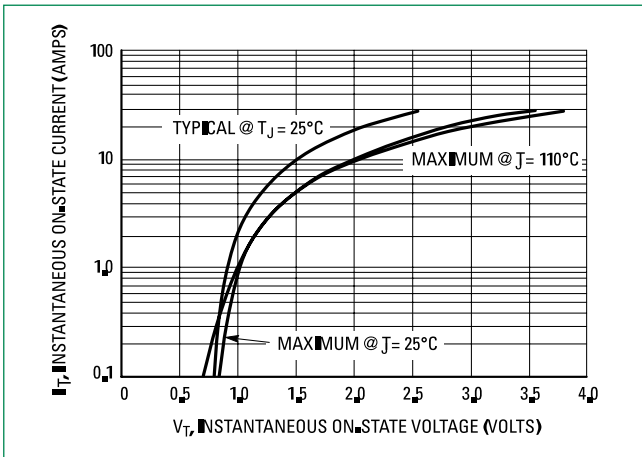## Figure 2. On-State Power Dissipation

Figure 3. On–State Characteristics

Figure 4. Transient Thermal Response

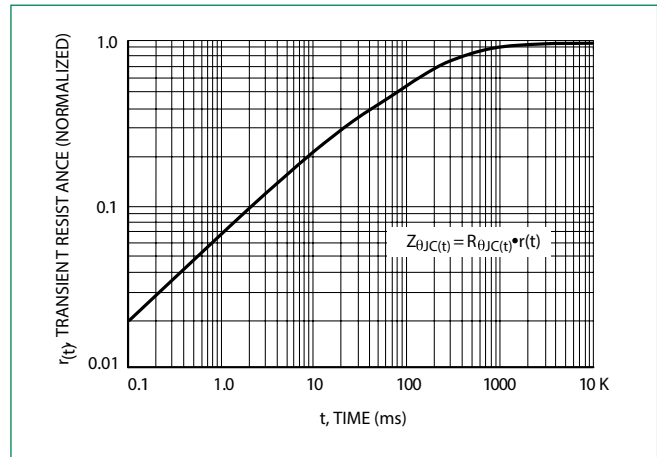$$Z_{\theta JC(t)} = R_{\theta JC(t)} \bullet r(t)$$

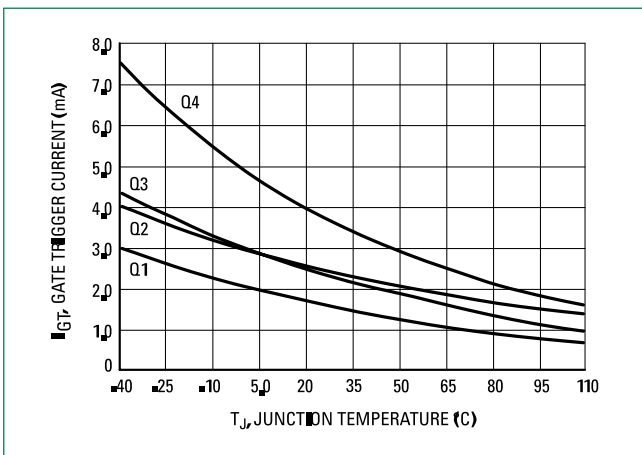## Figure 5. Typical Gate Trigger Current vs, Junction Temperature

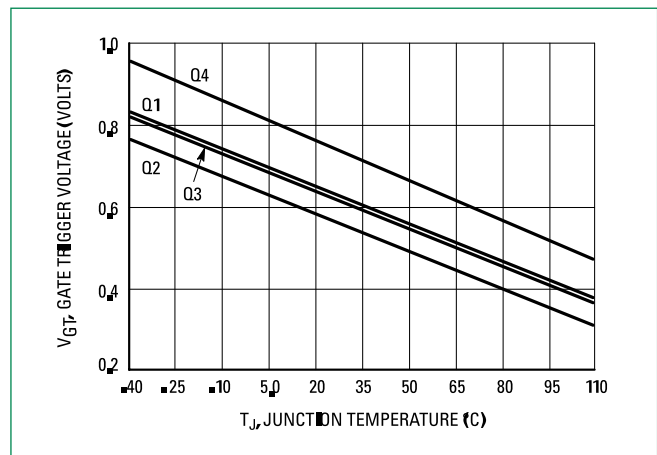## Figure 6. Typical Gate Trigger Voltage vs. Junction Temperature

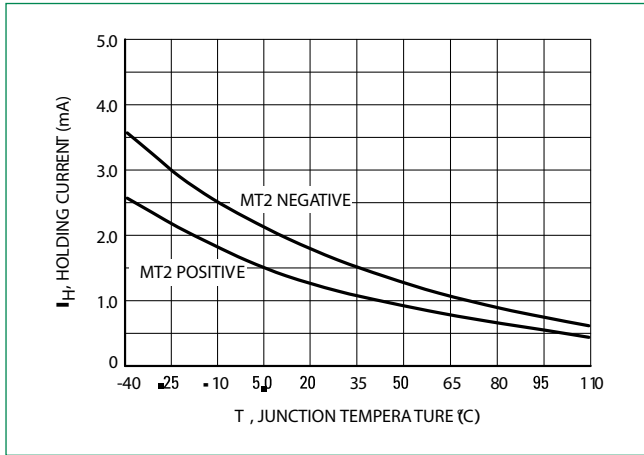## Figure 7. Typical Holding Current vs. Junction Temperature

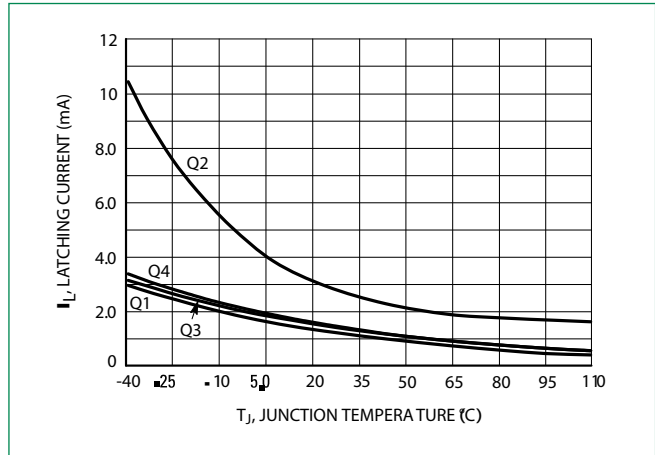## Figure 8. Typical Latching Current vs. Junction Temperature

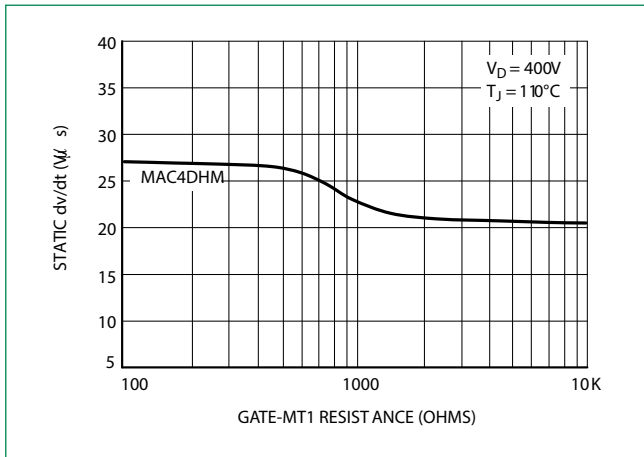## Figure 9. Exponential Static dv/dt vs. Gate–MT1 Resistance, MT2(+)

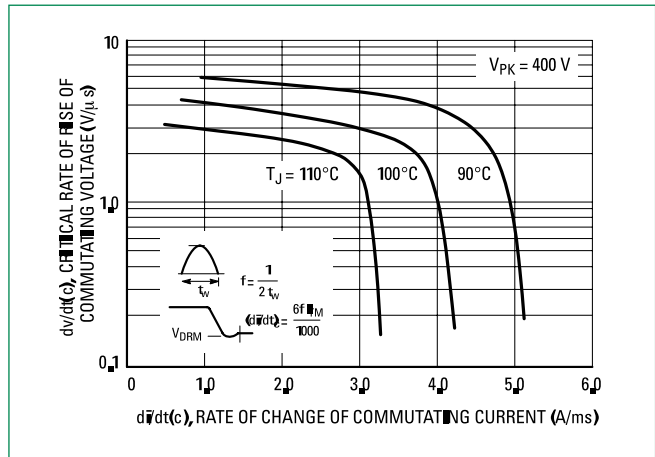## Figure 10. Exponential Static dv/dt vs. Gate–MT1 Resistance, MT2(-)

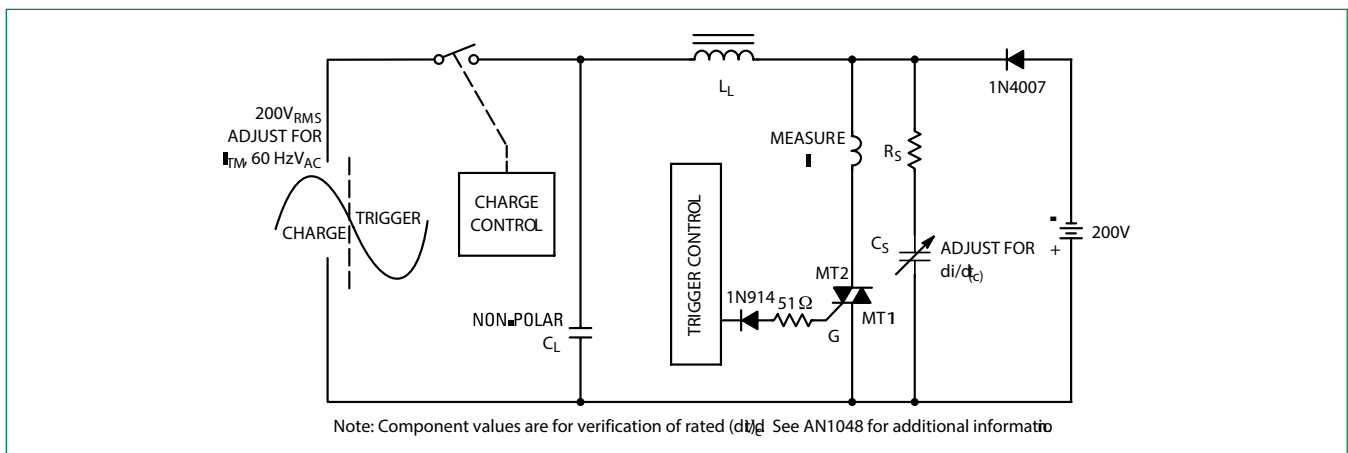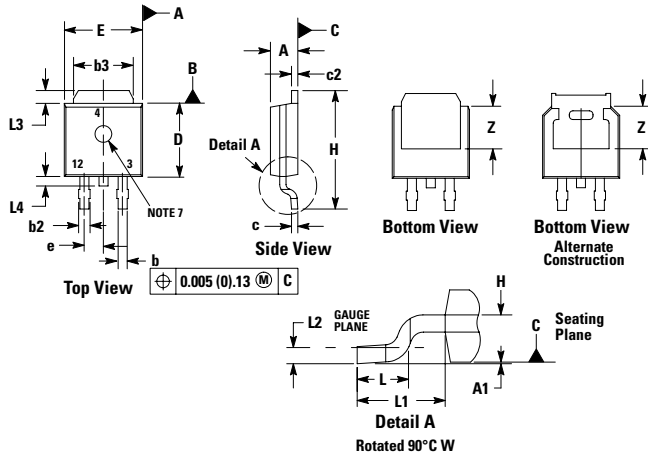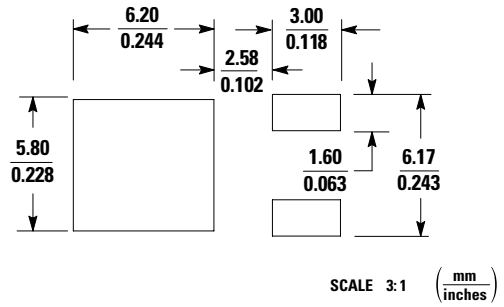## Figure 11. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)

Note: Component values are for verification of rated (di/dt)$_c$. See AN1048 for additional information

Dimensions

Soldering Footprint

SCALE 3:1 $\left(\dfrac{mm}{inches}\right)$

Dim	Inches		Millimeters	
	Min	Max	Min	Max
A	0.087	0.094	2.20	2.40
A1	0.000	0.005	0.00	0.12
b	0.022	0.030	0.55	0.75
b2	0.026	0.033	0.65	0.85
b3	0.209	0.217	5.30	5.50
c	0.019	0.023	0.49	0.59
c2	0.019	0.023	0.49	0.59
D	0.213	0.224	5.40	5.70
E	0.252	0.260	6.40	6.60
e	0.091		2.30	
H	0.374	0.406	9.50	10.30
L	0.058	0.070	1.47	1.78
L1	0.114		2.90	
L2	0.019	0.023	0.49	0.59
L3	0.053	0.065	1.35	1.65
L4	0.028	0.039	0.70	1.00
Z	0.154	-	3.90	-

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982.
2. CONTROLLING DIMENSION: INCH. STYLE 6: PIN 1. MT1
3. MT2
4. GATE
5. MT2

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Dimensions

DPAK-3
Case 369D-01
Issue B

TO251-3L POD
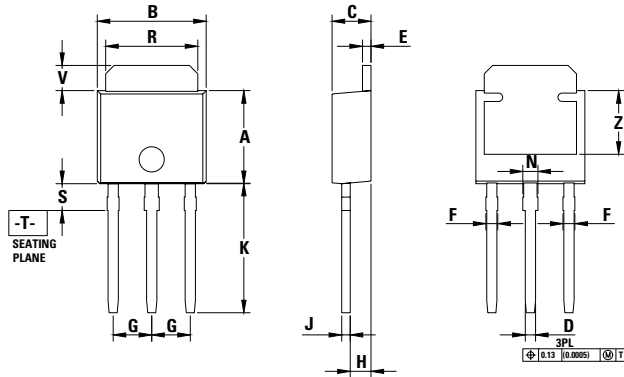
Dim	Inches		Millimeters	
	Min	**Max**	**Min**	**Max**
A	0.213	0.224	5.40	5.70
B	0.252	0.260	6.40	6.60
C	0.087	0.094	2.20	2.40
D	0.024	0.030	0.60	0.75
E	0.022	0.026	0.55	0.65
F	0.023	0.031	0.58	0.78
G	0.091 TYP.		2.30 TYP.	
H	0.046	0.050	1.18	1.28
J	0.019	0.023	0.49	0.59
K	0.291	0.315	7.40	8.00
N	0.031	0.039	0.78	0.98
R	0.209	0.217	5.30	5.50
S	0.063 TYP.		1.60 TYP	
V	0.053	0.065	1.35	1.65
Z	0.150 TYP.		3.80 TYP.	

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
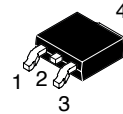2. CONTROLLING DIMENSION: INCH. STYLE 6: PIN 1. MT1
3. MT2
4. GATE
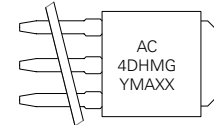5. MT2

Part Marking System

DPAK-3
Case 369C
Style 6
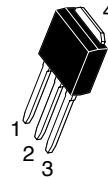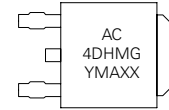
DPAK-3
Case 369D
Style 6

AC4DCx	=Device Code
x	=D, M, or N
Y	=Year
M	=Month
A	=Assembly Site
XX	=Lot Serial Code
G	=Pb-Free Package

Pin Assignment

Pin Assignment	
1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	Main Terminal 2

Ordering Information

Device	Package Type	Package	Shipping
MAC4DHM–001	DPAK–3	369D	4000 Units / Box
MAC4DHM–001G	DPAK–3 (Pb–Free)	369D	4000 Units / Box
MAC4DHMT4	DPAK–3	369C	2500 / Tape & Reel
MAC4DHMT4G	DPAK–3 (Pb–Free)	369C	2500 / Tape & Reel

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